

**FEATURES**

Low equivalent on-resistance


**SOT-23**
**MAXIMUM RATINGS**( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

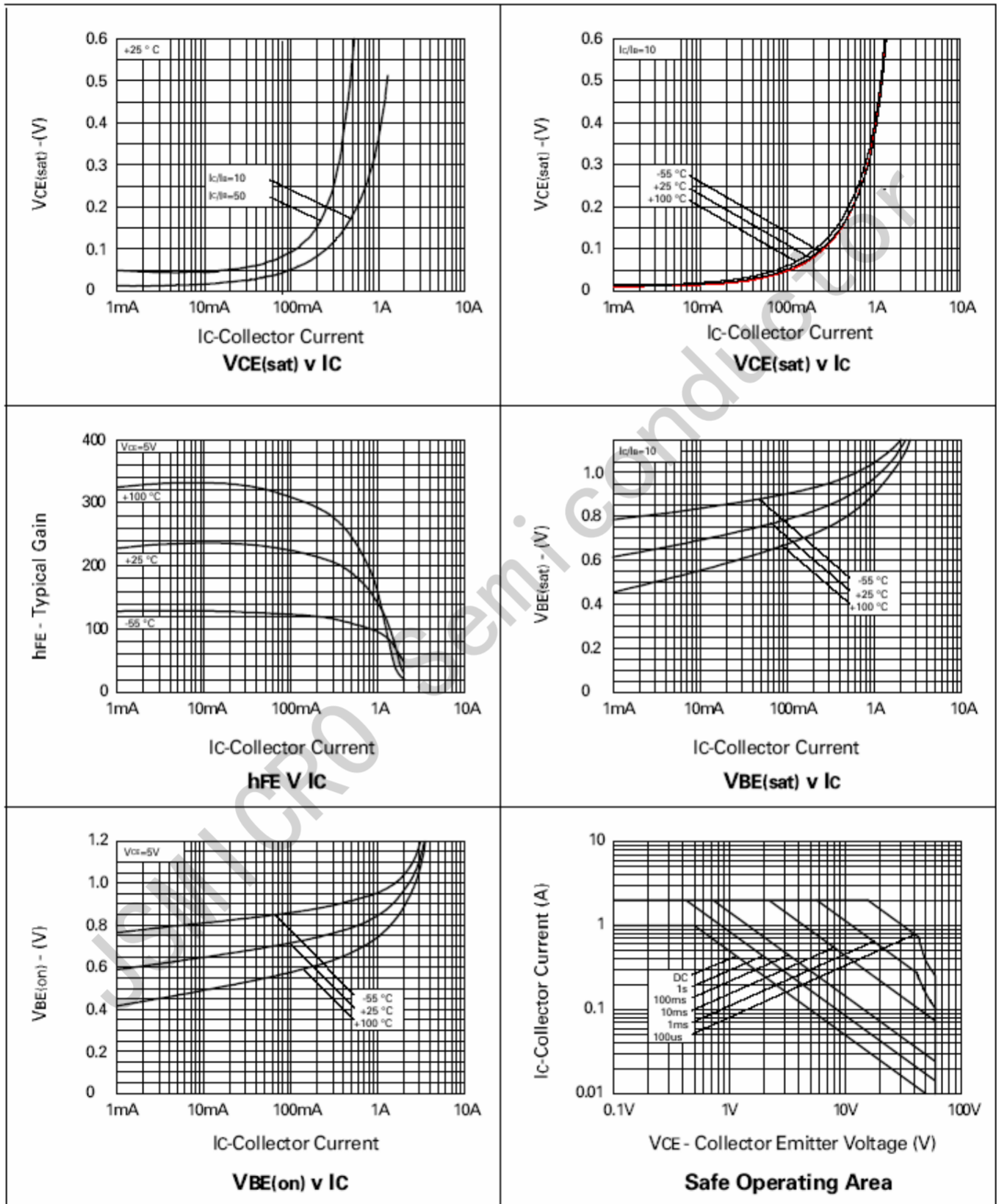
Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	80	V
$V_{CEO}$	Collector-Emitter Voltage	60	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	1	A
$P_C$	Collector Power Dissipation	250	mW
$T_j$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^{\circ}\text{C}$

**ELECTRICAL CHARACTERISTICS** ( $T_{amb}=25^{\circ}\text{C}$  unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	80			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^1$	$I_C=10\text{mA}, I_B=0$	60			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=60\text{V}, I_E=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=1\text{mA}$	100			
	$h_{FE(2)}^1$	$V_{CE}=5\text{V}, I_C=500\text{mA}$	100		300	
	$h_{FE(3)}^1$	$V_{CE}=5\text{V}, I_C=1\text{A}$	80			
	$h_{FE(4)}^1$	$V_{CE}=5\text{V}, I_C=2\text{A}$	30			
Collector-emitter saturation voltage	$V_{CE(sat)1}^1$	$I_C=500\text{mA}, I_B=50\text{mA}$			0.25	V
	$V_{CE(sat)2}^1$	$I_C=1\text{A}, I_B=100\text{mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}^1$	$I_C=1\text{A}, I_B=100\text{mA}$			1.1	V
Base-emitter voltage	$V_{BE}^1$	$V_{CE}=5\text{V}, I_C=1\text{A}$			1	V
Transition frequency	$f_T$	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	150			MHz
Collector output capacitance	$C_{ob}$	$V_{CB}=10\text{V}, f=1\text{MHz}$			10	pF

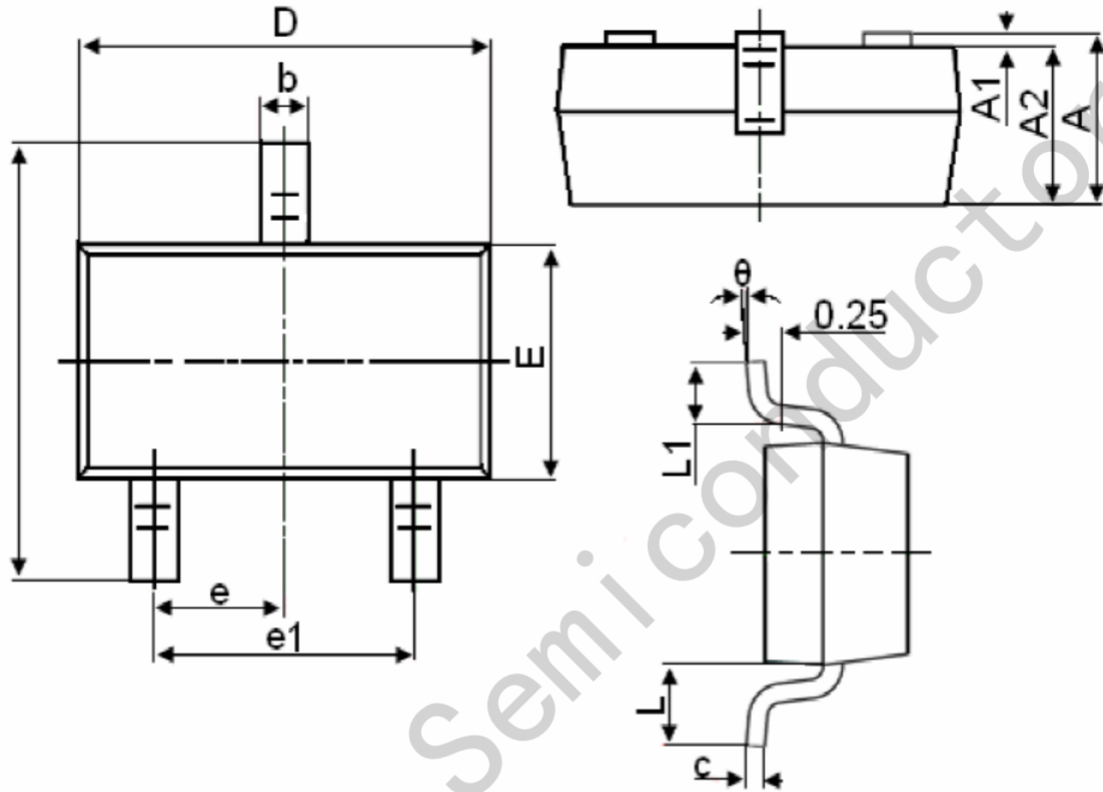
<sup>1</sup>Measured under pulsed conditions, Pulse width=300 $\mu\text{s}$ , Duty cycle $\leq 2\%$ .

**Typical Characteristics**



## Package Information

SOT-23



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Bipolar Transistors - BJT category](#):*

*Click to view products by [JSMSEMI manufacturer](#):*

Other Similar products are found below :

[BC559C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [NJVMJD148T4G](#) [NTE16](#) [NTE195A](#) [IMX9T110](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SB1204S-TL-E](#) [2SC5488A-TL-H](#) [FMC5AT148](#) [2N2369ADCSM](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC4618TLN](#) [CPH6501-TL-E](#) [BC856BW-13-F](#) [US6T6TR](#) [BAX18/A52R](#) [BC556/112](#) [IMZ2AT108](#) [MMST8098T146](#) [MCH6102-TL-E](#) [BC846B-13-F](#) [2N3879](#) [30A02MH-TL-E](#) [NTE13](#) [NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [JANTX2N2920L](#) [JANSR2N2907AUB](#) [CMLT3946EG TR](#) [SNSS40600CF8T1G](#) [CMLT3906EG TR](#) [GRP-DATA-JANS2N2907AUB](#) [GRP-DATA-JANS2N2222AUA](#) [MMDT3946FL3-7](#) [2N4240](#) [JANS2N3019](#) [MSB30KH-13](#) [2N2221AUB](#) [2SD1815T-TL-E](#) [2N6678](#) [2N2907Ae4](#)